

WR0553 M M $\approx g^{\sim} \parallel 1$

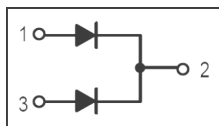
Schottky Barrier Diode in a TO-220 Plastic Package.

$$\Omega^{\alpha} H_1 \in \tilde{\omega}^{\alpha}$$

Low power loss, high efficiency.

[illegible]

For use in low voltage,high frequency inverters, free wheeling, and polarity protection applications.

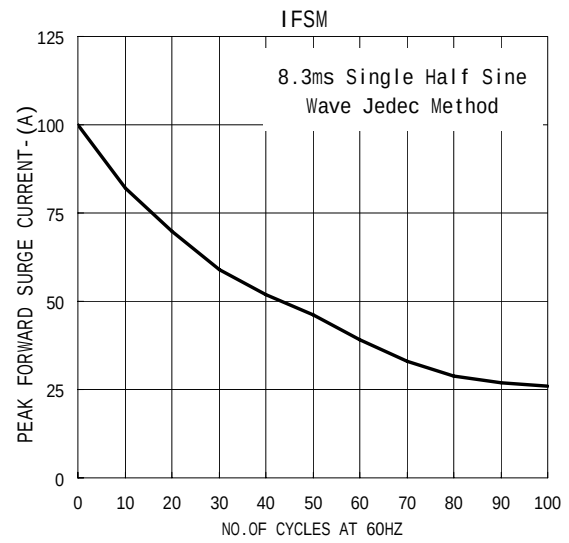
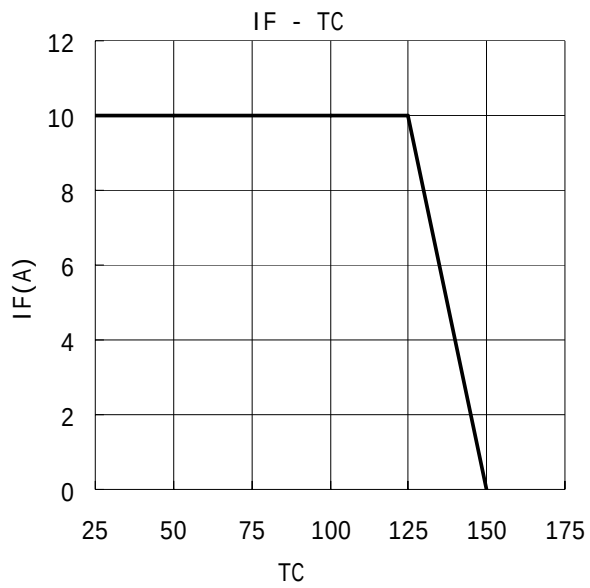


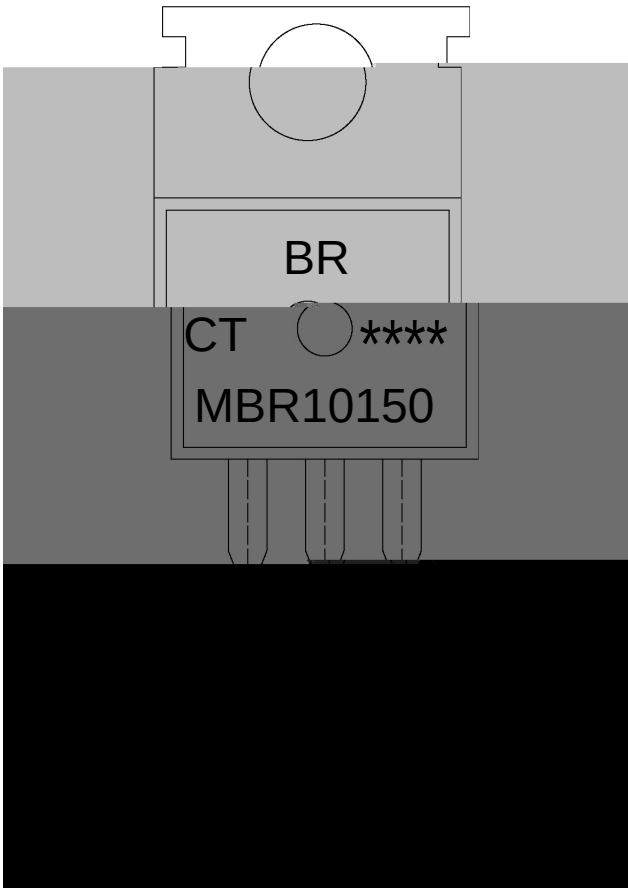
PIN1 Anode PIN 2 Cathode PIN 3 Anode

M 1 " See Marking Instructions.

Parameter	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	150	V
Peak Repetitive Forward Current	$I_{F(AV)}$	10	A
Average Rectified Forward Current	I_{FRM}	10	A
Non-Repetitive Peak Forward Surge Current	I_{FSM}	150	A
Repetitive Peak Reverse Surge Current	I_{RRM}	0.5	A
Thermal Resistance Junction to Case	$R_{\theta JC}$	2.5	/W
Junction and Storage Temperature Range	T_j, T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse Current Voltage	V_R	$I_R=1mA$	150			V
Forward Voltage	V_F	$I_F=5A$			0.88	V
		$I_F=5A(T_c=125^\circ C)$			0.78	V
Instantaneous Reverse Current	I_R	$V_R=150V$			0.15	mA
		$V_R=150V(T_c=125^\circ C)$			150	mA
Voltage Rate of Change	dv/dt				10000	V/ μs





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P EU43483 X	ꯏ ꯑ ꯍ ꯑ ꯍ
FW:	ꯏ ꯑ ꯍ ꯑ
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Note:	
BR:	Company Code
MBR10150 X	Product Type.
CT:	Internal Structure
****:	Lot No. Code, code change with Lot No.

